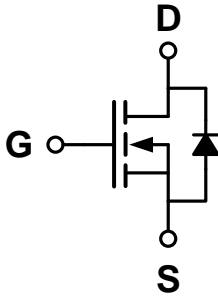
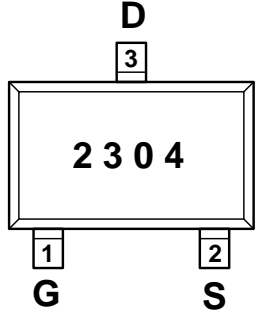


<p><b>DESCRIPTION</b></p> <p>The JXP2304VRG uses advanced trench technology to provide excellent <math>R_{DS(ON)}</math>, low gate charge and high density cell Design for ultra low on-resistance. This device is suitable for use as a load switch or in PWM applications.</p> <p><b>GENERAL FEATURES</b></p> <ul style="list-style-type: none"> <li>◇ <math>V_{DS} = 30V</math>, <math>I_D = 3.6A</math></li> <li style="padding-left: 20px;"><math>R_{DS(ON)}(Typ.) = 39m\Omega</math> @ <math>V_{GS} = 4.5V</math></li> <li style="padding-left: 20px;"><math>R_{DS(ON)}(Typ.) = 24m\Omega</math> @ <math>V_{GS} = 10V</math></li> <li>◇ High power and current handling capability</li> <li>◇ Lead free product is acquired</li> <li>◇ Surface mount package</li> </ul> <p><b>APPLICATION</b></p> <ul style="list-style-type: none"> <li>◇ PWM applications</li> <li>◇ Load switch</li> </ul> <p><b>PACKAGE</b></p> <ul style="list-style-type: none"> <li>◇ SOT-23</li> </ul>	<p><b>SCHEMATIC DIAGRAM</b></p>  <p><b>PIN ASSIGNMENT</b></p> <p style="text-align: center;">SOT-23 (TOP VIEW)</p> 
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### ORDERING INFORMATION

Part Number	Storage Temperature	Package	Marking	Devices Per Reel
JXP2304VRG	-55°C to +150°C	SOT-23	2304	3000

### ABSOLUTE MAXIMUM RATINGS

( $T_A = 25^\circ C$  unless otherwise noted)

parameter	symbol	limit	unit
Drain-source voltage	$V_{DS}$	30	V
Gate-source voltage	$V_{GS}$	$\pm 20$	V
Continuous drain current ( $T_J = 150^\circ C$ ) <sup>a</sup>	$I_D$	$T_A = 25^\circ C$	3.6
		$T_A = 70^\circ C$	3.0
Pulsed drain current <sup>b</sup>	$I_{DM}$	14.4	A
Continuous source current (diode conduction) <sup>a</sup>	$I_S$	0.6	
Power dissipation <sup>a</sup>	$P_D$	$T_A = 25^\circ C$	0.71
		$T_A = 70^\circ C$	0.46
Operating junction and storage temperature range	$T_J, T_{stg}$	-55—150	°C

## THERMAL CHARACTERISTICS

Parameter		Symbol	Typ	Max	Unit
Maximum junction-to-ambient <sup>a</sup>	≤ 5 s	R <sub>θJA</sub>	120	145	°C/W
	Steady-State		140	175	
Maximum junction-to-foot	Steady-State	R <sub>θJC</sub>	62	78	

**Notes**

- a. Surface mounted on 1" x 1" FR4 board  
b. Pulse width limited by maximum junction temperature

## ELECTRICAL CHARACTERISTICS (T<sub>A</sub>=25°C unless otherwise noted)

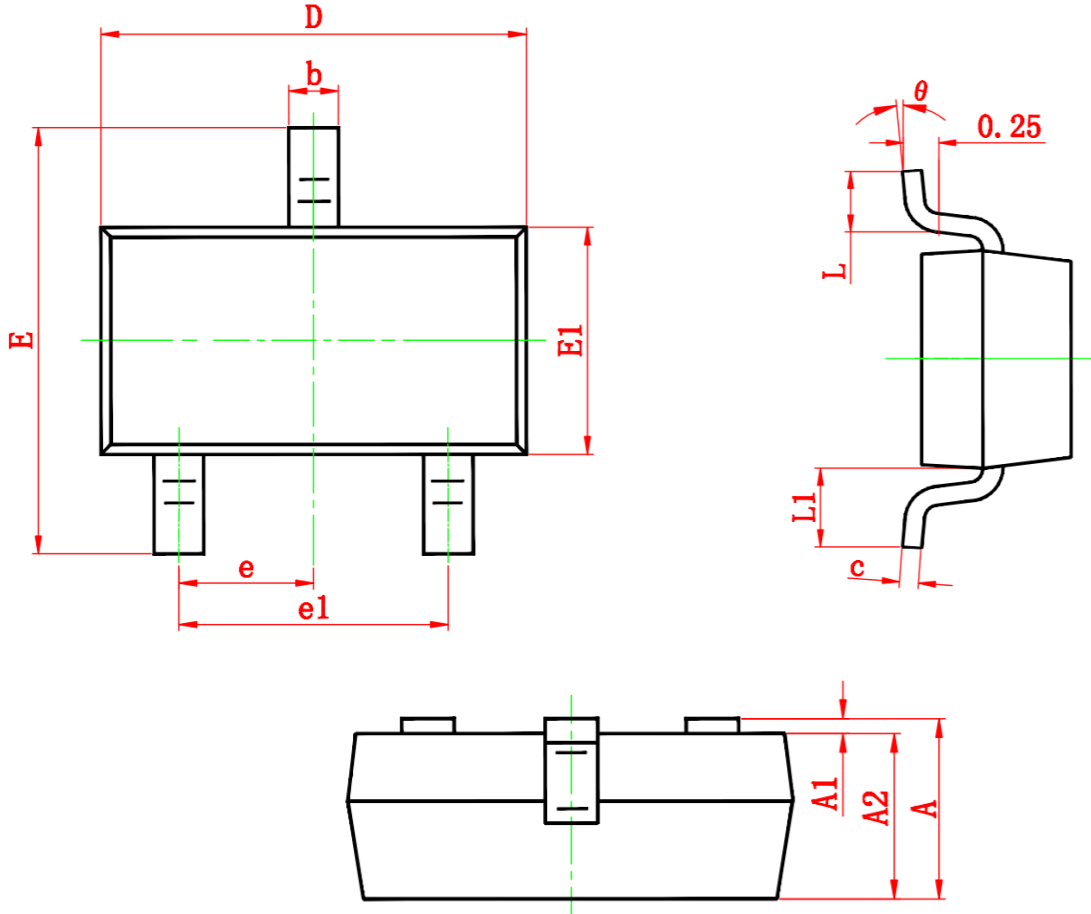
Parameter	Symbol	Condition	Min	Typ	Max	Unit
<b>OFF Characteristics</b>						
Drain-source breakdown voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V, I <sub>D</sub> =250μA	30	-	-	V
Zero gate voltage drain current	I <sub>DSS</sub>	V <sub>DS</sub> =30V, V <sub>GS</sub> =0V	-	-	1	μA
Gate-body leakage	I <sub>GSS</sub>	V <sub>DS</sub> =0V, V <sub>GS</sub> =±20V	-	-	±100	nA
<b>ON Characteristics</b>						
Gate threshold voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =250μA	1.0	1.5	2.0	V
Drain-source on-state resistance <sup>a</sup>	R <sub>DS(ON)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =3.6A	-	24	30	mΩ
		V <sub>GS</sub> =4.5V, I <sub>D</sub> =3A		39	48	
Forward transconductance <sup>a</sup>	g <sub>fs</sub>	V <sub>DS</sub> =5V, I <sub>D</sub> =3.6A	-	11	-	S
<b>Dynamic Characteristics <sup>b</sup></b>						
Input capacitance	C <sub>ISS</sub>	V <sub>DS</sub> =15V, V <sub>GS</sub> =0V f=1.0MHz	-	230	-	pF
Output capacitance	C <sub>OSS</sub>		-	40	-	
Reverse transfer capacitance	C <sub>RSS</sub>		-	17	-	
<b>Switching Characteristics</b>						
Turn-on delay time	t <sub>D(ON)</sub>	V <sub>DS</sub> =15V V <sub>GS</sub> =10V R <sub>L</sub> =6 ohm R <sub>GEN</sub> =3ohm	-	10	-	ns
Rise time	t <sub>r</sub>		-	50	-	
Turn-off delay time	t <sub>D(OFF)</sub>		-	10	-	
Fall time	t <sub>f</sub>		-	20	-	
Total gate charge	Q <sub>g</sub>	V <sub>DS</sub> =15V, I <sub>D</sub> =3.6A V <sub>GS</sub> =10V	-	40	-	nC
Gate-source charge	Q <sub>gs</sub>		-	0.75	-	
Gate-drain charge	Q <sub>gd</sub>		-	0.65	-	
<b>DRAIN-SOURCE DIODE CHARACTERISTICS</b>						
Diode forward voltage	V <sub>SD</sub>	V <sub>GS</sub> =0V, I <sub>S</sub> =1A	-	0.76	1.16	V

**Notes**

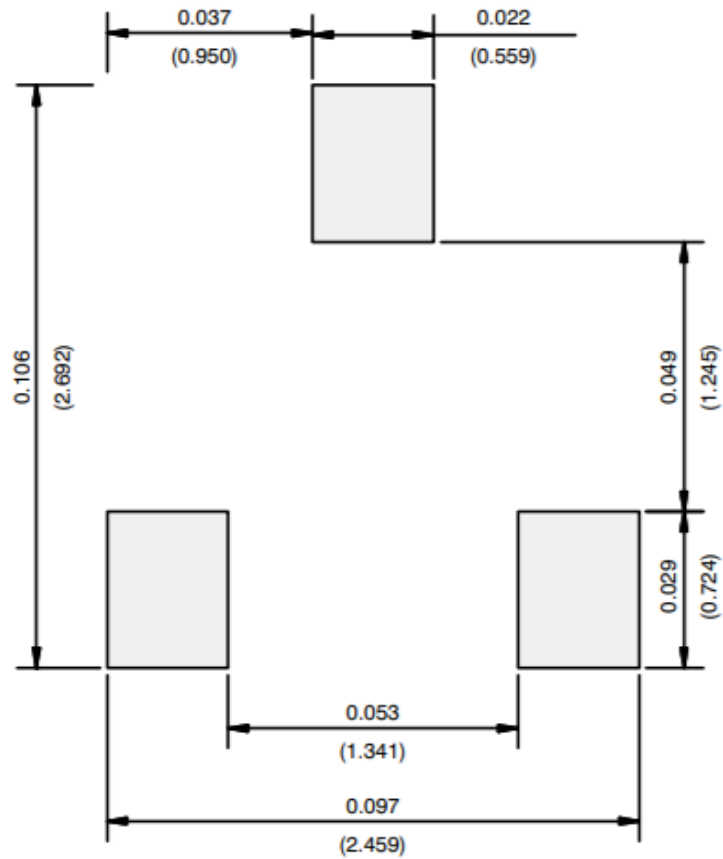
- a. Pulse test: Pulse width ≤ 300 μs, duty cycle ≤ 2 %  
b. Guaranteed by design, not subject to production testing

## PACKAGE INFORMATION

- SOT-23



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	0.900	1.150	0.035	0.045
A1	0.000	0.100	0.000	0.004
A2	0.900	1.050	0.035	0.041
b	0.300	0.500	0.012	0.020
c	0.080	0.150	0.003	0.006
D	2.800	3.000	0.110	0.118
E	2.250	2.550	0.089	0.100
E1	1.200	1.400	0.047	0.055
e	0.950 TYP.		0.037 TYP.	
e1	1.800	2.000	0.071	0.079
L	0.300	0.500	0.012	0.020
L1	0.550 REF.		0.022 REF.	
$\theta$	0°	8°	0°	8°

**RECOMMENDED MINIMUM PADS FOR SOT-23**

Recommended Minimum Pads  
Dimensions in Inches/(mm)